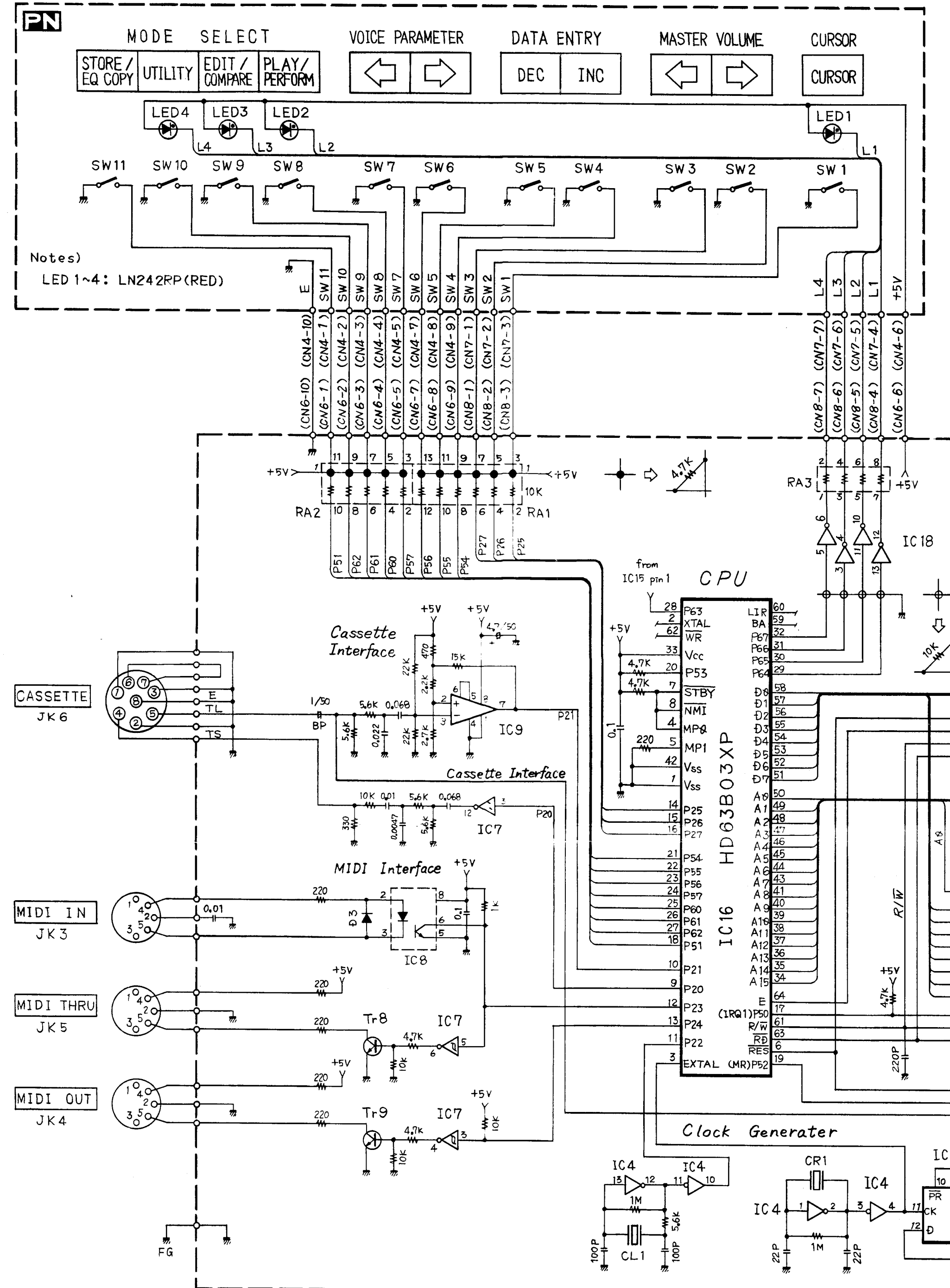




Notes)

IC 1 : NJM4558DV (16001390)
 2,10 : NJM072D (1G107000)
 3 : NJM4556 (1G042500)
 4 : TC40H004P (1G051000)
 5 : TC40H074P (1G051100)
 6 : PST518B-2 (1G116200)
 7 : SN74HC14N (1R001450)
 8 : TLP552 (1K000470)
 9 : IR9311 (1G134900)
 11 : SN74HC138N (1R013850)
 12 : YM3012 (1T301200)
 13 : YM2414 (XB768001)
 14 : RAM TC5664PL-20 (XA606001)
 15 : ROM 64K (XB186002)
 16 : HD63B03XP (1G140800)
 17 : SN74HC32N (1R003250)
 18 : SN74HC04N (1R000450)

D 1-3: 1SS176

Resistor Δ marked: Metal Oxide Resistor

RA 1 : 4.7K x 6 + 10K x 6
 2 : 4.7K x 5 + 10K x 5
 3 : 390 x 4

CL 1 : Ceramic Resonator 500KHz

CR 1 : Quartz Crystal Unit 7.15909MHz

EMI 1 : 0.022μF

B 1 : Lithium Battery CR2032

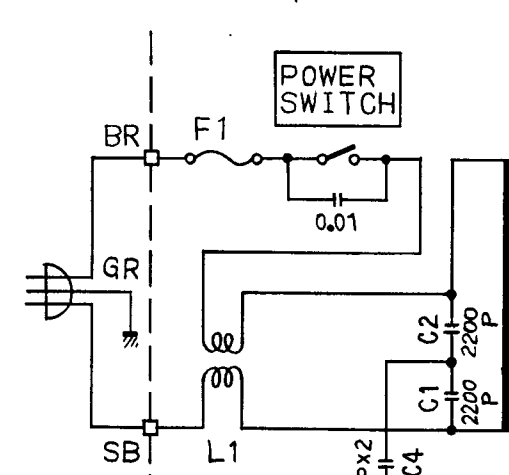
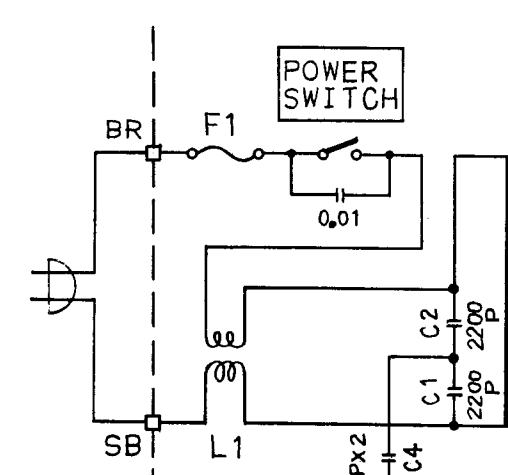
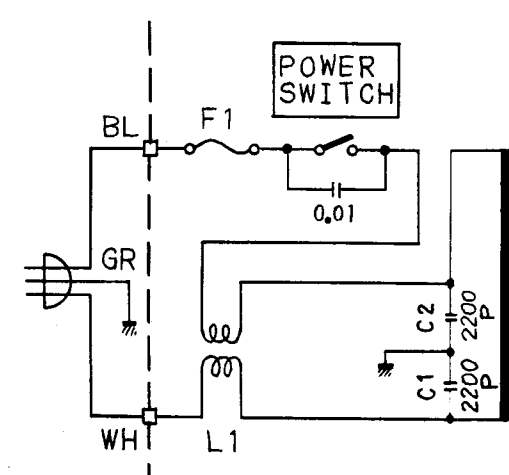
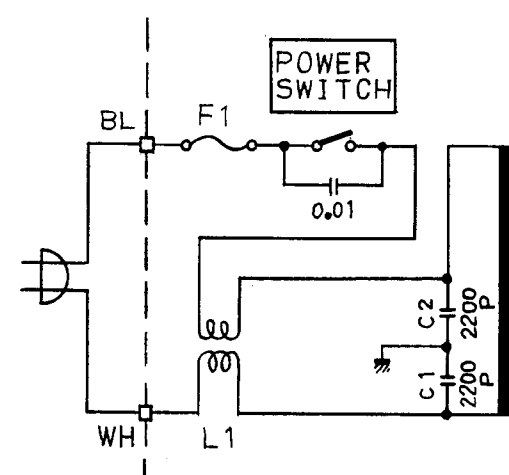
Tr 1,2 : 2SC2878 (A,B)
 3~6 : 2SA1115 (E,F)
 7~9 : 2SC2603 (E,F)

• U.S.American Spec.

• Canadian Spec.

• European Spec.

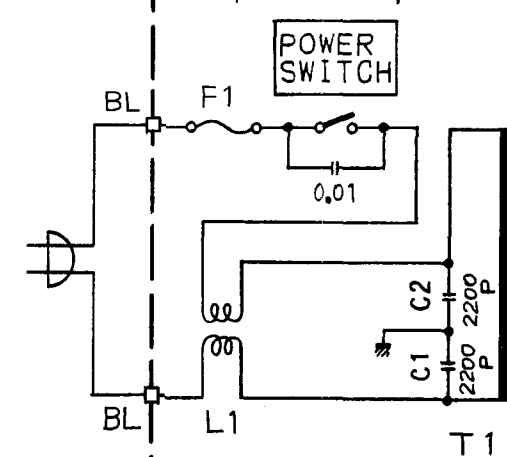
• Australian Spec.



	F 1	F 2	T 1
Japanese Spec.	▽ 0.5A 250V	▽ 1A 250V	XB357
U.S.American Spec.	ULST4 0.5A 250V	ULST4 1A 250V	XB358
West German, Australian North European Spec.	⊗ T500mA 250V	⊗ T630mA 250V	XB359

KEC-91115-65 1/2 Δ

• Japanese Spec.



Notes)

IC 1 : AN78M15F (XB466001)
 2 : AN79M15F (XB467001)
 3 : AN78M05F (XB646001)

D 1 : 1D4B1
 2 : SIRBA10
 L 1 : PLA3021A